



ZXT13N20DE6

20V NPN LOW SATURATION SWITCHING TRANSISTOR

Features

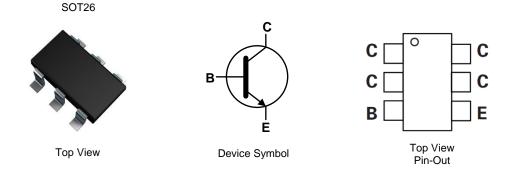
- $BV_{CEO} > 20V$
- I_C = 4.5A Continuous Collector Current
- I_{CM} = 15A Peak Pulse Current
- $R_{CE(SAT)} = 38m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage (75mV max @ 1A)
- hFE Characterized up to 15A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT26 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (93)
- Weight: 0.015 grams (Approximate)

Applications

- **DC–DC** Converters
- **Power Management Functions**
- **Power Switches**
- Motor Control



Ordering Information (Note 4)

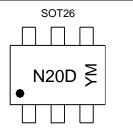
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT13N20DE6TA	AEC-Q101	N20D	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



N20D = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M or \overline{M} = Month (ex: 9 = September)

Date (Code	Key
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Notes:

Year	201	5	201	6	2017	2018	2019	2020	202	1 20	22 2	2023	2024	2025
Code	С		D		E	F	G	Н	I		J	К	L	М
Mont	h	Ja	an	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	V _{EBO}	7.5	V
Base Current	IB	500	mA
Continuous Collector Current	lc	4.5	А
Peak Pulse Collector Current	I _{СМ}	15	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)			W	
Linear Derating Factor	(Note 6)	– P _D	1.7 13.6	mW/°C	
Thermal Registered, Junction to Ambient	(Note 5)	P	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{θJA}	73		
Thermal Resistance, Junction to Lead	(Note 7)	R _{θJL}	18.6		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 25mm x 25mm 1oz copper that is on single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state.

6. Same as Note 6, except the device is measured at t \leq 5 sec.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



20

40

60

80

Temperature (°C) Derating Curve

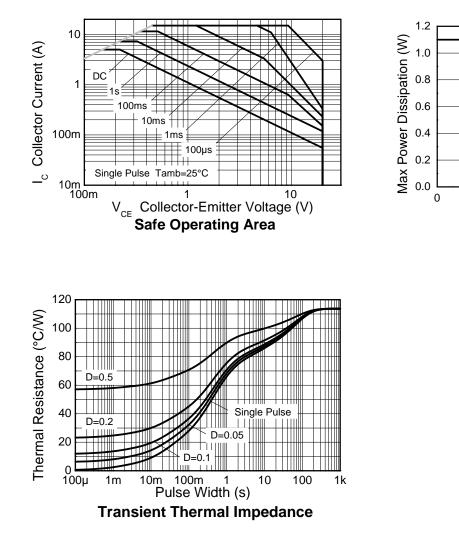
100

120

160

140

Thermal Characteristics and Derating Information







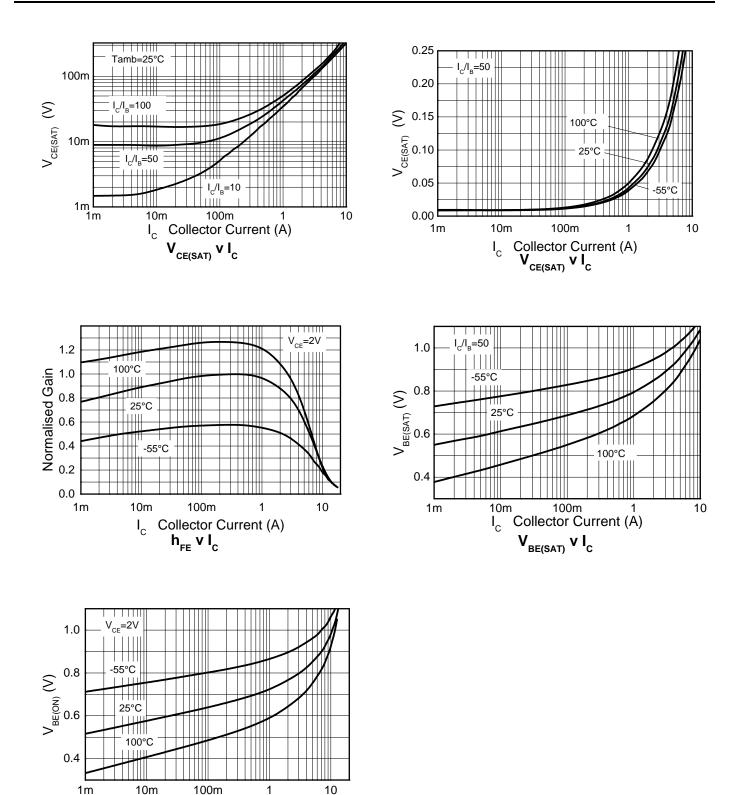
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	50	100	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	20	33	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7.5	8.5	_	V	I _E = 100μA
Collector-Base Cutoff Current	I _{CBO}	_	—	100	nA	$V_{CB} = 40V$
Emitter Cutoff Current	I _{EBO}	_	—	100	nA	$V_{EB} = 6V$
Collector-Emitter Cutoff Current	I _{CES}	_	—	100	nA	$V_{CES} = 40V$
ON CHARACTERISTICS (Note 9)						
		250	400	—		$I_{C} = 10mA, V_{CE} = 2V$
DC Current Gain	h	300	450	900		$I_C = 1A, V_{CE} = 2V$
	h _{FE}	200	300	—		$I_{C} = 5A, V_{CE} = 2V$
		15	45	—		$I_{C} = 15A, V_{CE} = 2V$
		—	5	8		$I_{C} = 100 \text{mA}, I_{B} = 10 \text{mA}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	55	75	mV	$I_{\rm C} = 1$ A, $I_{\rm B} = 10$ mA
		_	170	230		$I_{C} = 4.5A, I_{B} = 45mA$
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	0.85	0.90	V	$I_{C} = 4.5A, V_{CE} = 2V$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	fT	_	96	—	MHz	$V_{CE} = 10V, I_C = 50mA, f = 50MHz$
Output Capacitance	Cobo	—	50	_	pF	$V_{CB} = 10V, f = 1MHz$
Turn-On Time	t _(on)	—	115	—	ns	$V_{CC} = 10V, I_{C} = 2A$
Turn-Off Time	t _(off)	_	485	_	ns	$I_{B1} = I_{B2} = 40 \text{mA}$

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



I_c

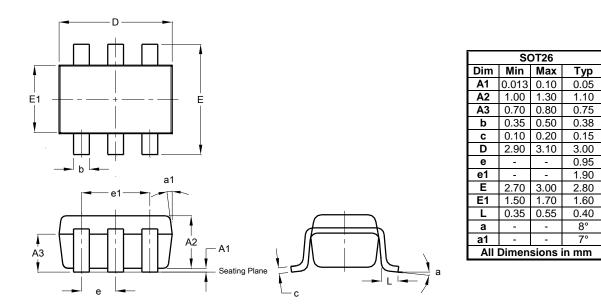
Collector Current (A)

 $\mathbf{V}_{_{\mathsf{BE}(\mathsf{ON})}} ~\mathbf{v}~\mathbf{I}_{_{\mathsf{C}}}$



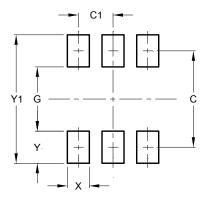
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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